

Applicant: Leonard Forbes

Title: SILICON-GERMANIUM DEVICES FOR CMOS FORMED BY ION IMPLANTATION AND  
SOLID PHASE EPITAXIAL REGROWTH

Docket No.: 303.229US2  
Filed: August 11, 1998  
Examiner: Mark Prenty  
Customer No.: 21186



Serial No.: 09/132157  
Due Date: October 9, 2003  
Group Art Unit: 2822  
Confirmation No.: 8931

RECEIVED  
OCT 17 2003  
TECHNOLOGY CENTER 2800


**MS Non-Fee Amendment**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- ☒ A return postcard.  
☒ An Amendment and Response (10 Pages).

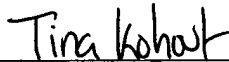
If not provided in a separate paper filed herewith, Please consider this a **PETITION FOR EXTENSION OF TIME** for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.  
Customer Number 21186

By:   
Atty: David C. Peterson  
Reg. No. 47,857

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS Non-Fee Amendment, Commissioner for Patents, P.O.Box 1450, Alexandria, VA 22313-1450, on this 9 day of October, 2003.

Name



Signature



SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.  
(GENERAL)

Customer Number 21186

S/N 09/132157

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes

Examiner: Mark Prently

Serial No.: 09/132157

Group Art Unit: 2822

Filed: August 11, 1998

Docket No.: 303.229US2

Title: SILICON-GERMANIUM DEVICES FOR CMOS FORMED BY ION  
IMPLANTATION AND SOLID PHASE EPITAXIAL REGROWTH



AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Commissioner for Patents  
P.O.Box 1450  
Alexandria, VA 22313-1450

Applicant has reviewed the Office Action mailed on July 9, 2003. Please amend the above-identified patent application as follows.

#41/Amend J  
PATENT  
G. Ford  
10/21/03

RECEIVED  
OCT 17 2003  
TECHNOLOGY CENTER 2800